TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process)

2SC2458

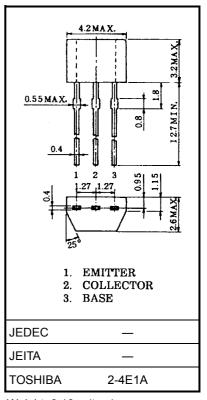
Audio Amplifier Applications

Unit: mm

- High current capability: IC = 150 mA (max)
- High DC current gain: $h_{FE} = 70 \sim 700$
- Excellent hFE linearity: hFE (IC = 0.1 mA)/hFE (IC = 2 mA) = 0.95 (typ.)
- Low noise: NF (2) = 1dB (typ.), 10dB (max)
- Complementary to 2SA1048.
- · Small package.

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Collector-base voltage	V_{CBO}	50	V	
Collector-emitter voltage	V _{CEO}	50	V	
Emitter-base voltage	V _{EBO}	5	V	
Collector current	IC	150	mA	
Base current	ΙΒ	50	mA	
Collector power dissipation	P _C	200	mW	
Junction temperature	Tj	125	°C	
Storage temperature range	T _{stg}	-55~125	°C	



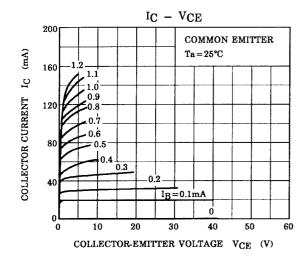
Weight: 0.13 g (typ.)

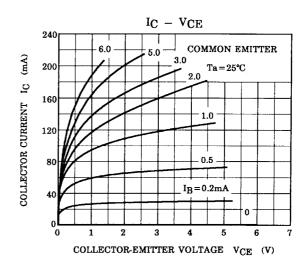
Electrical Characteristics (Ta = 25°C)

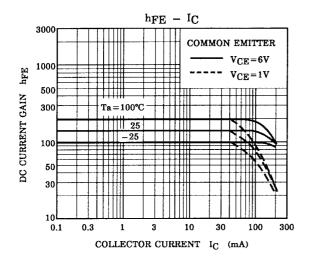
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = 50 \text{ V}, I_{E} = 0$	_	_	0.1	μА
Emitter cut-off current	I _{EBO}	$V_{EB} = 5 \text{ V}, I_{C} = 0$			0.1	μΑ
DC current gain	h _{FE} (Note)	V _{CE} = 6 V, I _C = 2 mA	70		700	
Collector-emitter saturation voltage	V _{CE (sat)}	$I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$	_	0.1	0.25	٧
Transition frequency	f _T	V _{CE} = 10 V, I _C = 1 mA	80	_	_	MHz
Collector output capacitance	C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz	_	2.0	3.5	pF
Noise figure	NF	$\begin{split} &V_{CE}=6~V,~I_{C}=0.1~mA,~f=1~kHz,\\ &R_{g}=10~k\Omega \end{split}$	_	1.0	10	dB

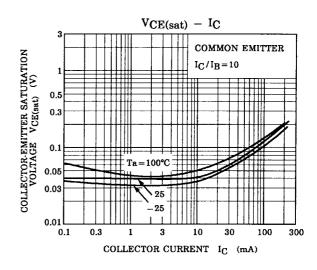
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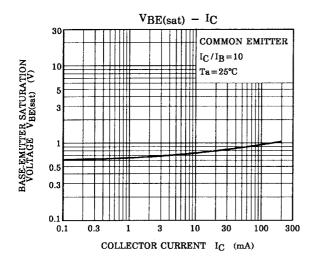
Note: hFE classification O: 70~140, Y: 120~240, GR: 200~400, BL: 350~700

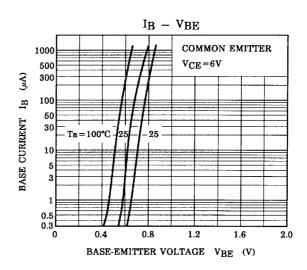




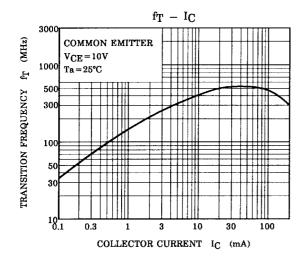


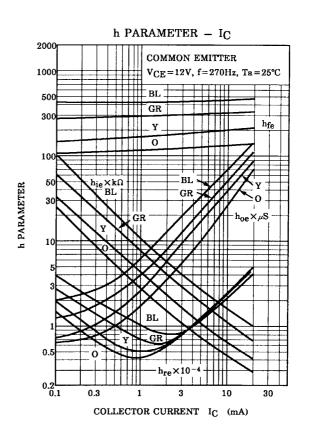


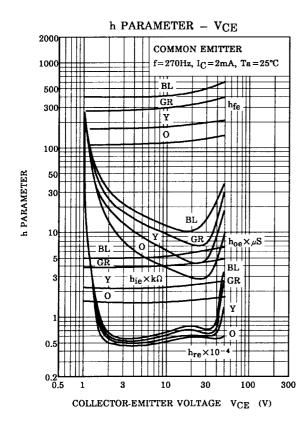


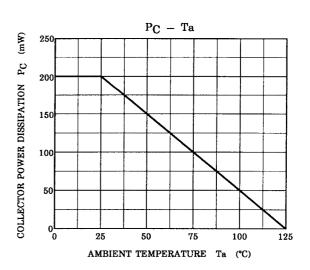


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